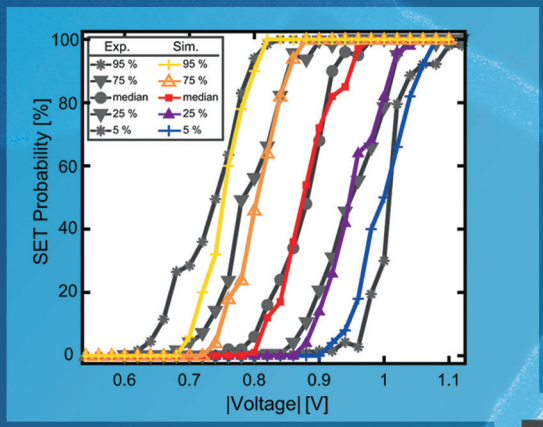

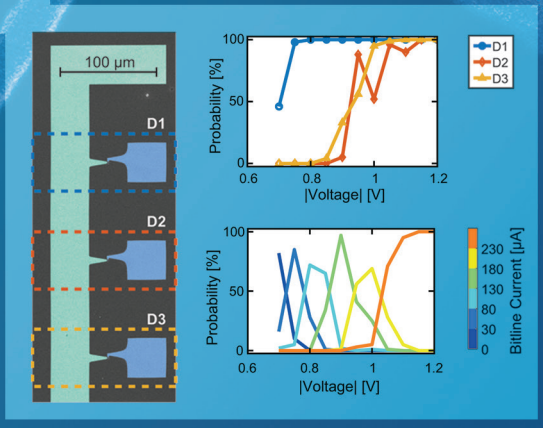

Hafnium oxide based memristive devices as functional elements of neuromorphic circuits

Felix Johannes Cüppers

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